

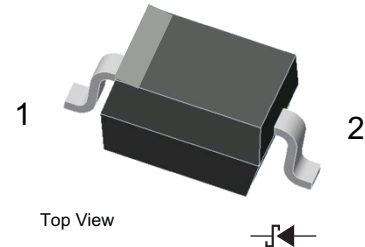
## Schottky Diodes

### PMEG1020EA

#### ■ Features

- Forward current: 2A
- Reverse voltage: 10V
- Ultra low forward voltage
- Very small plastic SMD package.

SOD-323



PIN DESCRIPTION

PIN	DESCRIPTION
1	Cathode
2	Anode

#### ■ Maximum Ratings $T_a=25^\circ\text{C}$

Parameter	Symbol	Value	Unit
Continuous reverse voltage	$V_R$	10	V
Continuous forward current	$I_F$	2	A
Repetitive peak forward current	$I_{FRM}$	3.2	
Non-repetitive peak forward current	$I_{FSM}$	9	
Thermal resistance from junction to ambient	$R_{thJA}$	450	$^\circ\text{C/W}$
		210	
thermal resistance from junction to solder point	$R_{thJS}$	90	
Junction temperature	$T_J$	150	$^\circ\text{C}$
Storage temperature	$T_{STG}$	-65 to +150	
Operating ambient temperature	$T_{amb}$	-65 to +150	

Note: 1. Refer to SOD-323 standard mounting conditions.

2. Device mounted on an FR4 printed-circuit board with copper clad 10x10mm.

3. Solder point of cathode tab.

#### ■ Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise specified.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse breakdown voltage	$V_R$	$I_R=100\ \mu\text{A}$	10			V
Forward voltage	$V_F$	see Fig.1; note 1 $I_F=0.01\text{A}$ $I_F=0.1\text{A}$ $I_F=1\text{A}$ $I_F=2\text{A}$			130 200 350 450	mV
Reverse current	$I_R$	see Fig.2; note 2 $V_R=5\text{V}$ $V_R=8\text{V}$ $V_R=10\text{V}$			2 2.5 3	mA
Diode capacitance	$C_D$	$V_R=5\text{V}$ , $f=1\text{MHz}$ ; see Fig.3			45	pF

Note 1. Pulse test:  $t_p=300\ \mu\text{s}$ ;  $\delta=0.02$ .

2. For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses (PR) are a significant part of the total power losses.

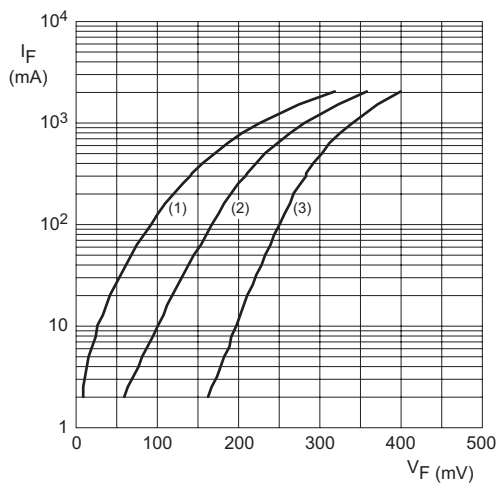
#### ■ Marking

Marking	E2
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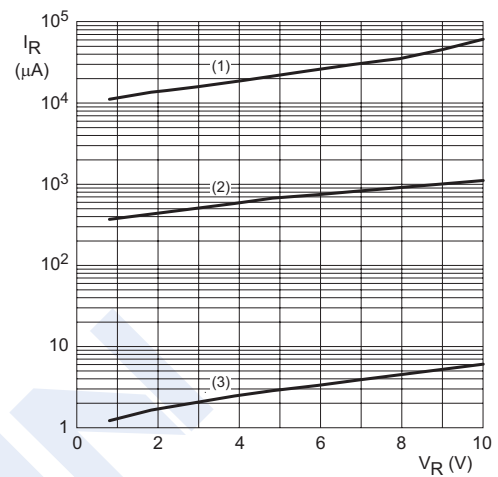
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#### ■ Typical Characteristics



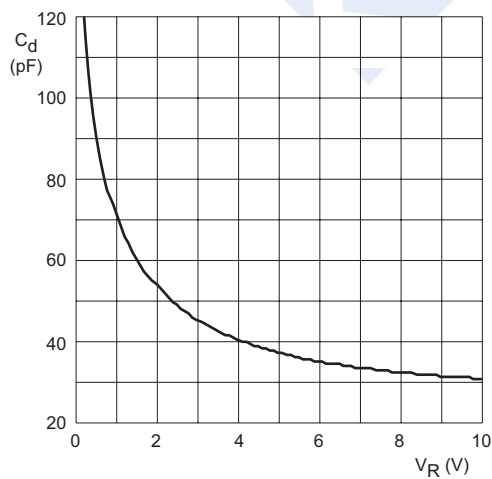
- (1)  $T_{amb} = 85\text{ }^{\circ}\text{C}$ .  
 (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
 (3)  $T_{amb} = -40\text{ }^{\circ}\text{C}$ .

Fig.1 Forward current as a function of forward voltage; typical values.



- (1)  $T_{amb} = 85\text{ }^{\circ}\text{C}$ .  
 (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
 (3)  $T_{amb} = -40\text{ }^{\circ}\text{C}$ .

Fig.2 Reverse current as a function of reverse voltage; typical values.



$f = 1\text{ MHz}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

Fig.3 Diode capacitance as a function of reverse voltage; typical values.

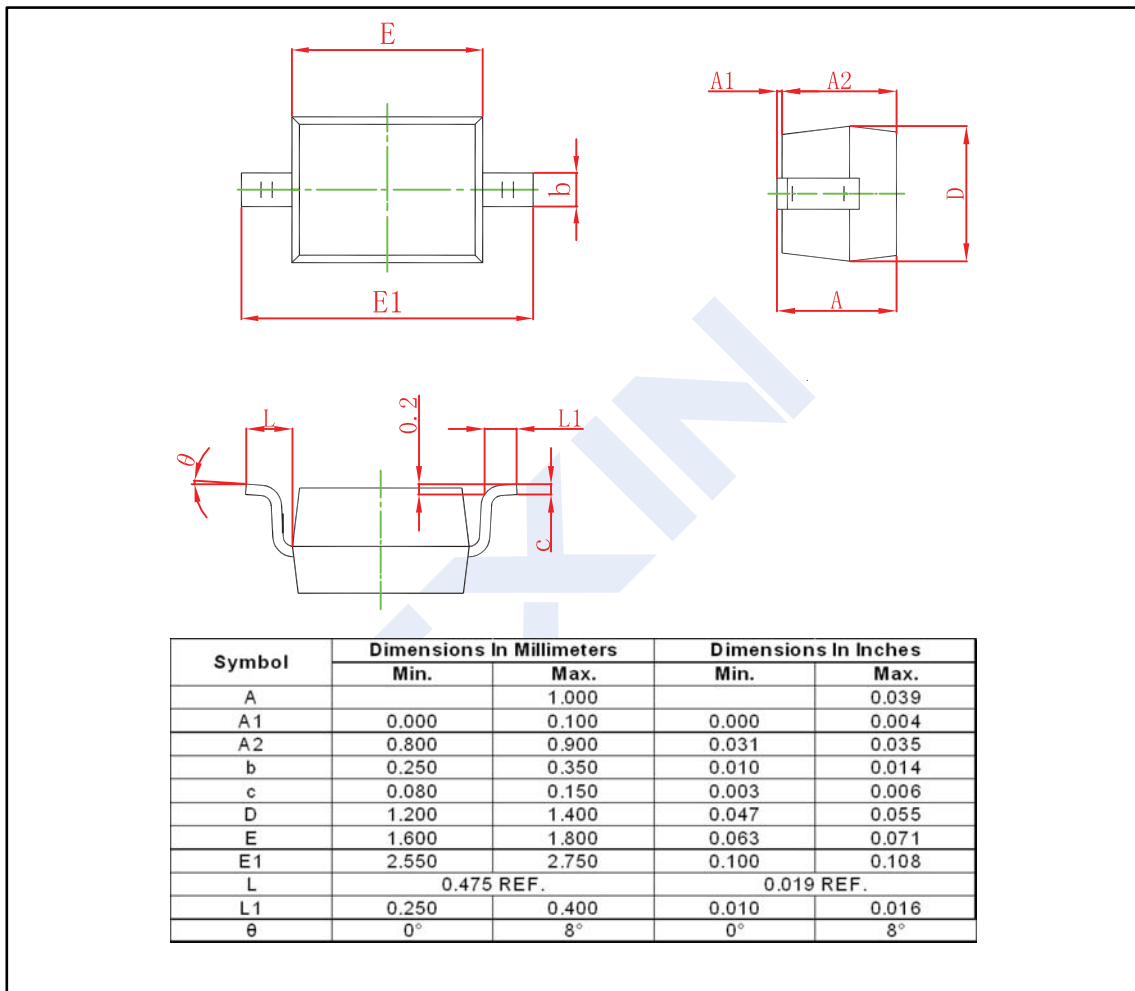
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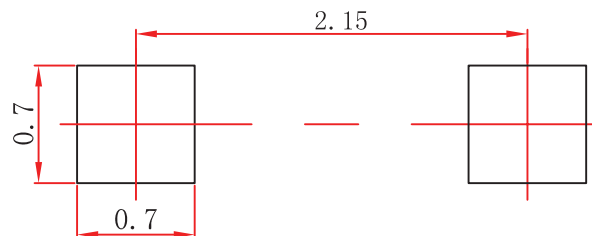
#### ■ Package Outline Dimensions

Plastic surface mounted package; 2 leads

SOD-323



#### ■ The Recommended Mounting Pad Size



#### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.